Power LDMOS transistor Rev. 2 — 1 September 2015

Product profile 1.

1.1 General description

A 250 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 600 MHz band.

Table 1. **Application information**

	Test signal	f	V _{DS}	PL	G _p	η _D
		(MHz)	(V)	(W)	(dB)	(%)
Ī	pulsed RF	108	50	250	28	72

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1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 600 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

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2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
BLF182X	(R (SOT1121A)	·	
1	drain1		
2	drain2	1 2	
3	gate1		
4	gate2		3
5	source		
			۲
			2 sym117
BLF182X	(RS (SOT1121B)		
1	drain1	~~~~	
2	drain2		1
3	gate1		
4	gate2	3 4 5	3
5	source	[1]	
			l IF-1
			2 sym117

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number Package				
Name Description			Version	
BLF182XR	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A	
BLF182XRS	-	earless flanged ceramic package; 4 leads	SOT1121B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	135	V
V _{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

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5. Thermal characteristics

Table 5. Thermal characteristics						
Symbol	Parameter	Conditions		Тур	Unit	
R _{th(j-c)}	thermal resistance from junction to case	T _j = 115 °C	[1][2]	<tbd></tbd>	K/W	
Z _{th(j-c)}	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 µs; δ = 20 %	<u>[3]</u>	<tbd></tbd>	K/W	

[1] T_j is the junction temperature.

[3] See <tbd>.

6. Characteristics

Table 6. DC characteristics

 $T_i = 25 \ ^{\circ}C$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V _{GS} = 0 V; I _D = 1.0 mA	135	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 100 mA	1.25	1.8	2.25	V
V _{GSq}	gate-source quiescent voltage	V _{DS} = 50 V; I _D = 50 mA	-	1.6	-	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μA
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	14.3	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 3.5 A	-	0.43	-	Ω

Table 7. AC characteristics

 $T_j = 25 \ ^{\circ}C$; per section unless otherwise specified.

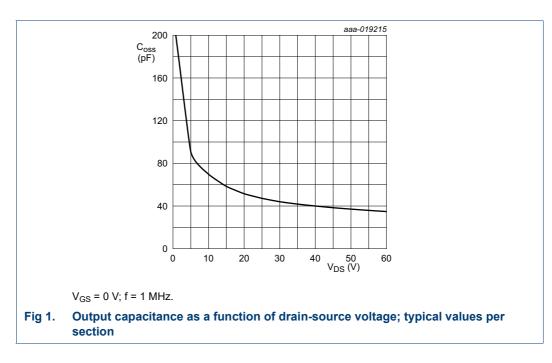
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	0.7	-	pF
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	116	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	37	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; $t_p = 100 \ \mu$ s; $\delta = 20 \ \%$; $f = 108 \ MHz$; RF performance at $V_{DS} = 50 \ V$; $I_{Dq} = 100 \ mA$; $T_{case} = 25 \ \%$; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	P _L = 250 W	<tbd></tbd>	28	-	dB
RL _{in}	input return loss	P _L = 250 W	-	-10	-	dB
η _D	drain efficiency	P _L = 250 W	<tbd></tbd>	72	-	%

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7. Test information

7.1 Ruggedness in class-AB operation

The BLF182XR and BLF182XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 100 mA; P_L = 250 W pulsed; f = 108 MHz.

7.2 Impedance information

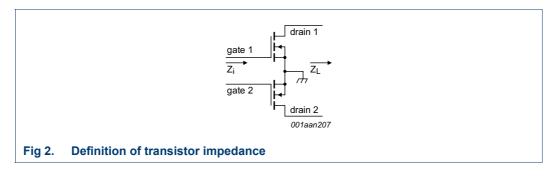


Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 50$ V and $P_L = 250$ W.

f	Z _i	ZL
(MHz)	(Ω)	(Ω)
108	<tbd></tbd>	<tbd></tbd>

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7.3 UIS avalanche energy

Table 10. Typical avalanche data per section

 $T_{amb} = 25 \, ^{\circ}C$; typical test data; test jig without water cooling.

I _{AS}	E _{AS}
(A)	(J)
<tbd></tbd>	<tbd></tbd>
<tbd></tbd>	<tbd></tbd>
<tbd></tbd>	<tbd></tbd>

For information see application note AN10273.

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8. Package outline

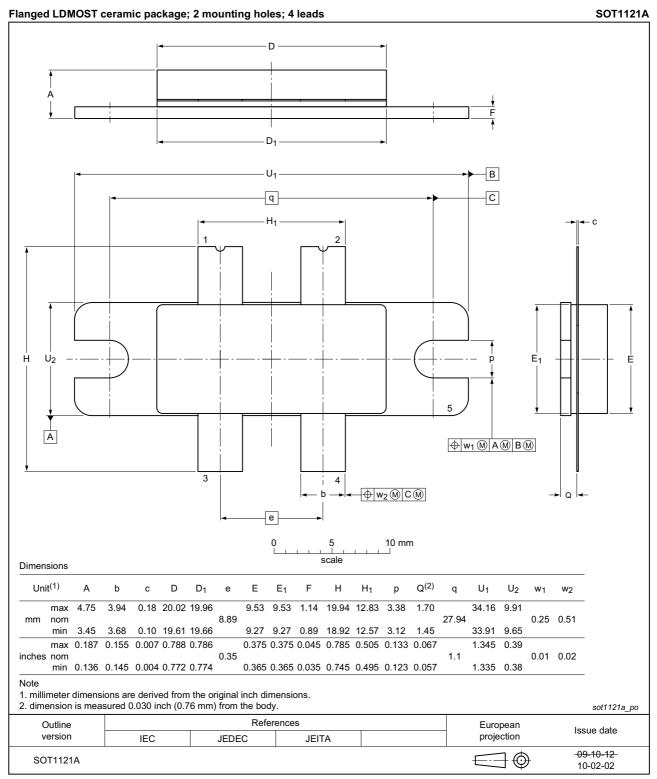


Fig 3. Package outline SOT1121A

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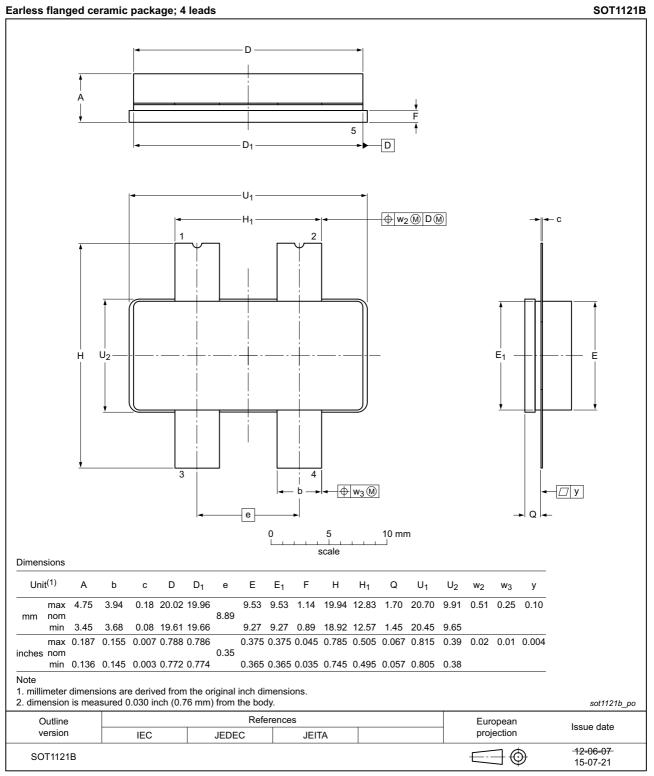


Fig 4. Package outline SOT1121B

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 11. Ab	Table 11. Abbreviations			
Acronym	Description			
CW	Continuous Wave			
ESD	ElectroStatic Discharge			
HF High Frequency				
LDMOS	Laterally Diffused Metal-Oxide Semiconductor			
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor			
MTF	Median Time to Failure			
SMD	Surface Mounted Device			
UIS	Unclamped Inductive Switching			
VSWR	Voltage Standing-Wave Ratio			

11. Revision history

Table 12.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF182XR_BLF182XRS#2	20150901	Objective data sheet	-	BLF182XR_BLF182XRS v.1
Modifications:	• The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.			
	 Legal texts have been adapted to the new company name where appropriate. 			
BLF182XR_BLF182XRS v.1	20150723	Objective data sheet	-	-

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12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[0] The medicate tetra of device (a) developed in this device of the second sec

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